Features

- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Collector – Emitter Voltage	MMBT5550 MMBT5551	V _{CEO}	140 160	Vdc
Collector – Base Voltage	MMBT5550 MMBT5551	V _{CBO}	160 180	Vdc
Emitter – Base Voltage		V _{EBO}	6.0	Vdc
Collector Current – Continuous		۱ _C	600	mAdc
Electrostatic Discharge Human Body Model Machine Model		ESD	> 8000 > 400	V

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit	
Total Device Dissipation FR– 5 Board (Note 1) @T _A = 25°C Derate Above 25°C	P _D	225 1.8	mW mW/°C	
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W	
Total Device Dissipation Alumina Substrate (Note 2) @T _A = 25°C Derate Above 25°C	P _D	300 2.4	mW mW/°C	
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W	
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

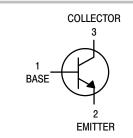
1. FR-5 = 1.0 \times 0.75 \times 0.062 in.

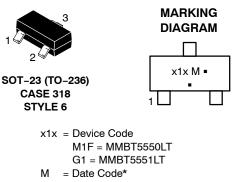
2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.



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= Pb–Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]		
MMBT5550LT1G, NSVMMBT5550LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
MMBT5550LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel		
MMBT5551LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
SMMBT5551LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
MMBT5551LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel		
SMMBT5551LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel		

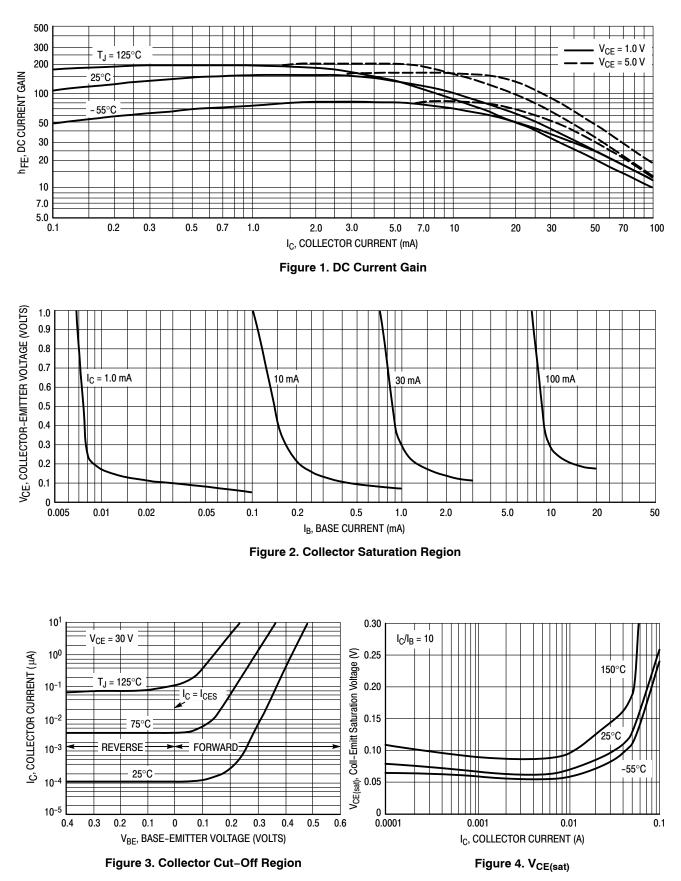
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

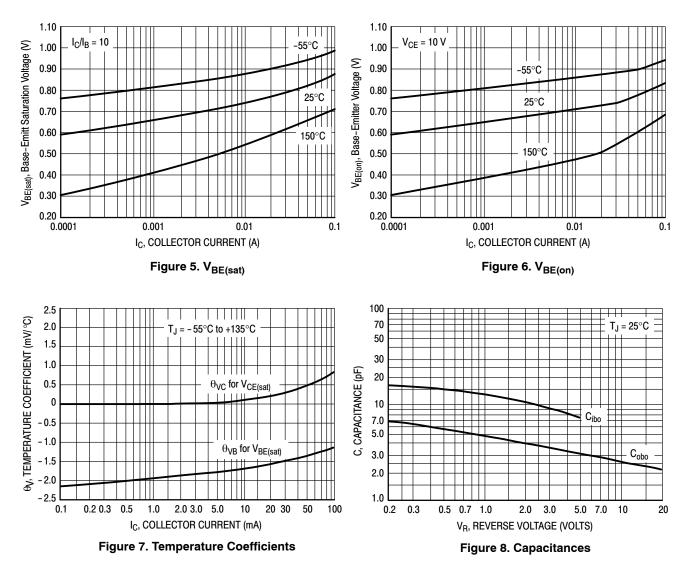
Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS			-		
Collector – Emitter Breakdown Voltage (Note 3) $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	MMBT5550 MMBT5551	V _{(BR)CEO}	140 160		Vdc
Collector – Base Breakdown Voltage $(I_C = 100 \ \mu Adc, I_E = 0)$	MMBT5550 MMBT5551	V _{(BR)CBO}	160 180		Vdc
Emitter – Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$		V _{(BR)EBO}	6.0	_	Vdc
	MMBT5550 MMBT5551 MMBT5550 MMBT5551	I _{CBO}	- - -	100 50 100 50	nAdc μAdc
Emitter Cutoff Current ($V_{EB} = 4.0 \text{ Vdc}, I_C = 0$)		I _{EBO}	-	50	nAdc
ON CHARACTERISTICS					
DC Current Gain ($I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 50 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$)	MMBT5550 MMBT5551 MMBT5550 MMBT5551 MMBT5550 MMBT5551	h _{FE}	60 80 60 80 20 30	 250 250 	-
Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc}$) ($I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$)	Both Types MMBT5550 MMBT5551	V _{CE(sat)}	- - -	0.15 0.25 0.20	Vdc
Base – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc}$) ($I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$)	Both Types MMBT5550 MMBT5551	V _{BE(sat)}	- - -	1.0 1.2 1.0	Vdc
Collector Emitter Cut-off $(V_{CB} = 10 \text{ V})$ $(V_{CB} = 75 \text{ V})$	Both Types	I _{CES}		50 100	nA

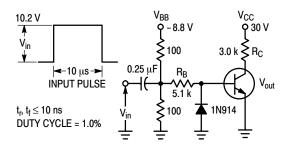
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2.0%.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

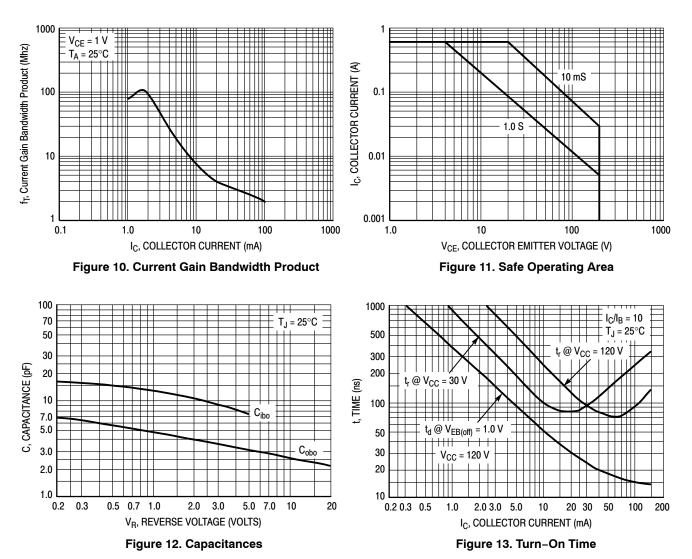




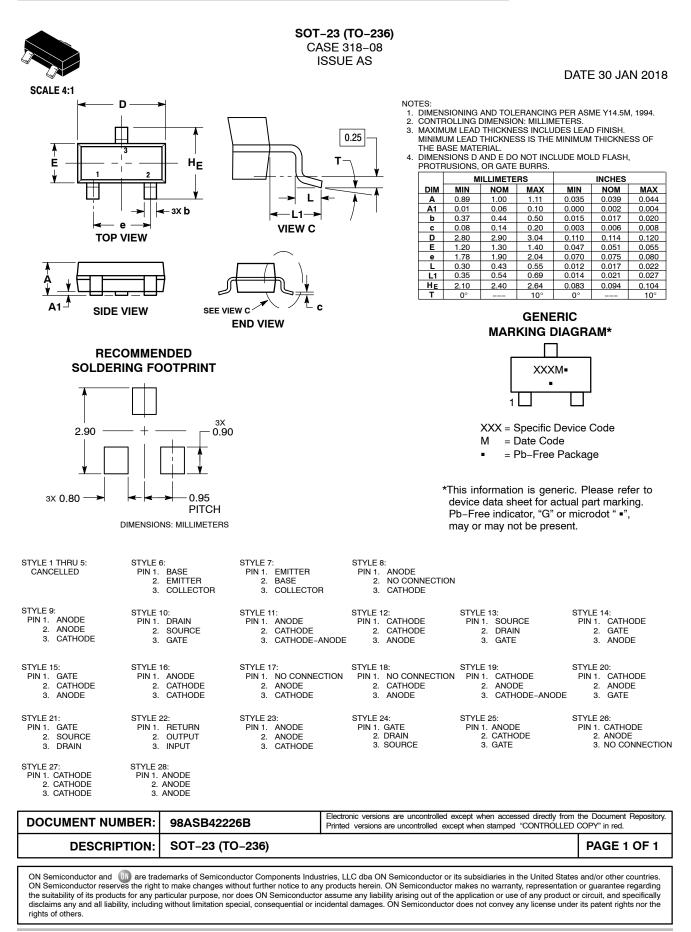
Values Shown are for $I_C \ensuremath{@} 10 \mbox{ mA}$

Figure 9. Switching Time Test Circuit

TYPICAL CHARACTERISTICS







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